



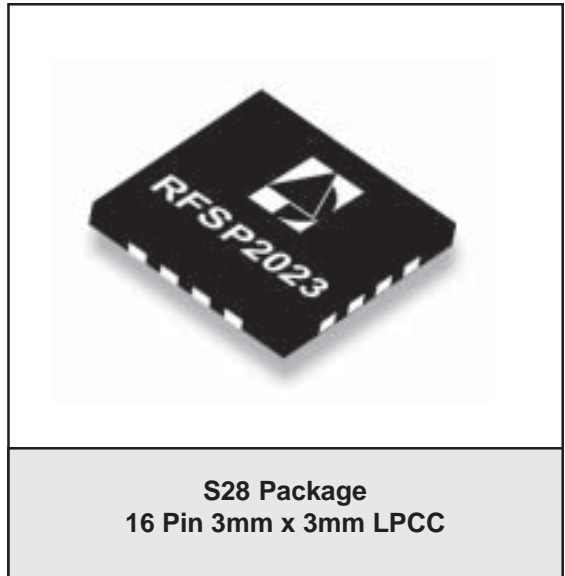
RFS P2023
 2.4 GHz 802.11b/g
 WLAN Power Amplifier
 Data Sheet - Rev 2.1

FEATURES

- <3% EVM, 145 mA @ P_{OUT}= +19 dBm with IEEE 802.11g Modulation at 54 Mbps
- -38 dBc ACPR 1st Sidelobe at +23 dBm with IEEE 802.11b Modulation at 11 Mbps
- -54 dBc ACPR 2nd Sidelobe at +23 dBm with IEEE 802.11b Modulation at 11 Mbps
- No RF Matching Required
- 34 dB of Linear Power Gain
- Temperature-Compensated Linear Power Detector

APPLICATIONS

- IEEE 802.11 b/g WLAN
- 2.4 GHz Cordless Phones
- 2.4 GHz ISM Equipment



PRODUCT DESCRIPTION

The RFS P2023 power amplifier is a high performance InGaP HBT IC designed for transmit applications in the 2.4-2.5 GHz band. The part is matched at the input and output so no additional RF matching components are required off-chip. The

PA exhibits unparalleled linearity and efficiency for both 802.11g and 802.11b WLAN systems. The power detector is temperature compensated on chip enabling a single-ended output voltage. The part is biased by a single +3.3 V supply.

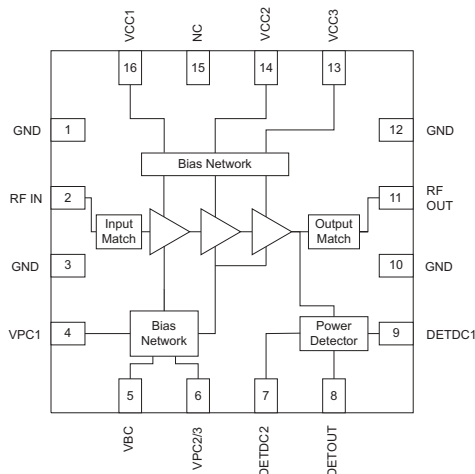


Figure 1: Block Diagram and Pinout

Table 1: Pin Description

PIN	NAME	DESCRIPTION	PIN	NAME	DESCRIPTION
1	GND	Ground	9	DET _{DC1}	Detector Bias 1
2	RF _{IN}	RF Input	10	GND	Ground
3	GND	Ground	11	RF _{OUT}	RF Output
4	V _{PC1}	Power Control 1	12	GND	Ground
5	V _{BC}	Bias Circuit Voltage	13	V _{CC3}	Supply Voltage
6	V _{PC2/3}	Power Control 2/3	14	V _{CC2}	Supply Voltage
7	DET _{DC2}	Detector Bias 2	15	NC	No Connect
8	DET _{OUT}	Power Detector Output	16	V _{CC1}	Supply Voltage

ELECTRICAL CHARACTERISTICS**Table 2: Absolute Minimum and Maximum Ratings**

PARAMETER	MIN	MAX	UNIT	COMMENTS
DC Power Supply (V_{CC1} , V_{CC2} , V_{CC3})		4.0	V	
Power Control Level (V_{PC1} , $V_{PC2/3}$)		4.0	V	Applied to series resistors external to V_{PC} pins. No RF signal applied.
DC Current Consumption		400	mA	
RF Input Level (RF_{IN})		-5	dBm	
Operating Ambient Temperature	0	+85	°C	
Storage Temperature	-55	+150	°C	

Stresses in excess of the absolute ratings may cause permanent damage. Functional operation is not implied under these conditions. Exposure to absolute ratings for extended periods of time may adversely affect reliability.

Table 3: Operating Ranges

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
Operating Frequency	2400	-	2500	MHz	
Supply Voltage (V_{CC1} , V_{CC2} , V_{CC3})	3.0	3.3	3.6	V	
Power Control Voltage (V_{PC1} , $V_{PC2/3}$)	-	3.3	-	V	PA_{ON} . Applied to series resistors external to V_{PC} pins.
	0	-	0.5	V	$PA_{SHUTDOWN}$. Applied to series resistors external to V_{PC} pins.

The device may be operated safely over these conditions; however, parametric performance is guaranteed only over the conditions defined in the electrical specifications.

Table 4: IEEE 802.11g Modulation, 54 Mbps OFDM
(V_{CC} = 3.3 V, V_{PC} = 3.3 V, P_{OUT} = +19 dBm, +25 °C)

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
Power Gain	31.5	34.5	37.0	dB	P _{OUT} = +19 dBm
Gain Ripple			±0.75	dB	
Current Consumption		145	165	mA	P _{OUT} = +19 dBm
Error Vector Magnitude (EVM)		2.8 -31	4.0 -28	% dB	P _{OUT} = +19 dBm P _{OUT} = +19 dBm
Power Detector Voltage	0.50	0.60	0.70	V	P _{OUT} = +19 dBm, 1KΩ Load
Detector Sensitivity		75		mV/dB	
Detector Output Impedance	1			KΩ	

Notes:

1. EVM includes noise floor of 1% (-40 dB).

Table 5: IEEE 802.11b Modulation, 11 Mbps DSSS, CCK
(V_{CC} = 3.3 V, V_{PC} = 3.3 V, P_{OUT} = +21 dBm, +25 °C)

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
Power Gain	31.5	34.5	37.0	dB	P _{OUT} = +21 dBm
Gain Ripple			±0.75	dB	
Current Consumption		175	195	mA	P _{OUT} = +21dBm
ACPR - 1st Sidelobe (11 MHz Offset)		-38	-33	dBc	P _{OUT} = +21 dBm; 1,2,5.5,11 Mbps
ACPR - 2nd Sidelobe (22 MHz Offset)		-54	-53	dBc	P _{OUT} = +21 dBm; 1,2,5.5,11 Mbps
Power Detector Voltage	0.7	0.8	0.9	V	P _{OUT} = +21 dBm, 1KΩ Load
Detector Sensitivity		75		mV/dB	
Detector Output Impedance	1			KΩ	

Table 6: Continuous Wave Signal
(V_{CC} = 3.3 V, V_{PC} = 3.3 V, +25 °C)

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
P1 dB	25.0	26.5	28.0	dBm	
Harmonics 2fo 3fo		-20 -25	-16 -20	dBc	
Stability		5:1			Pout = +25 dBm
Input Return Loss		-7	-4	dB	
Output Return Loss		-12	-9	dB	
Output Noise Power			130	dBm/Hz	
Reverse Isolation	40			dB	
Shutdown Current			1	μA	
Quiescent Current	30	45	60	mA	
T _{ON} Setting Time			1	μS	Settles within ±0.5 dB
T _{OFF} Setting Time			1	μS	

PERFORMANCE DATA

Figure 2: Gain, Current, EVM vs. Output Power at 2.412 GHz, 3.3 V (IEEE 802.11g @ 54 Mbps)

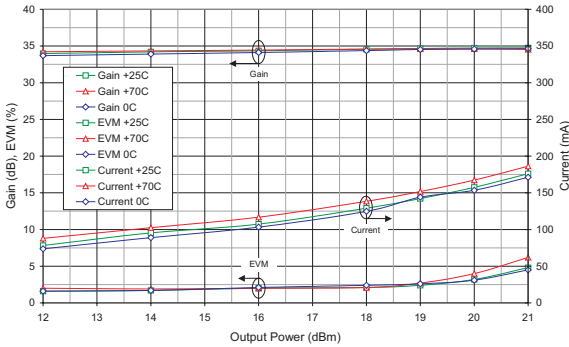


Figure 3: Gain, Current vs. Output Power at 2.412 GHz, 3.3 V (IEEE 802.11b Signal @ 11 Mbps)

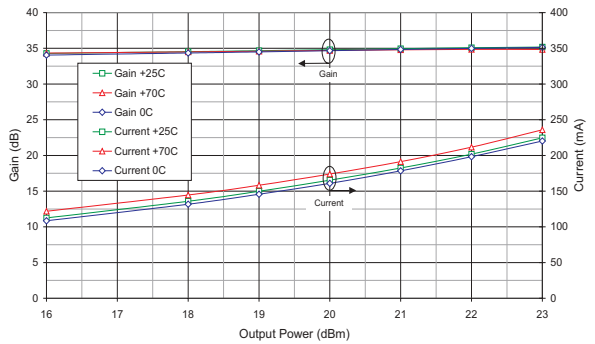


Figure 4: Gain, Current, EVM vs. Output Power at 2.437 GHz, 3.3 V (IEEE 802.11g @ 54 Mbps)

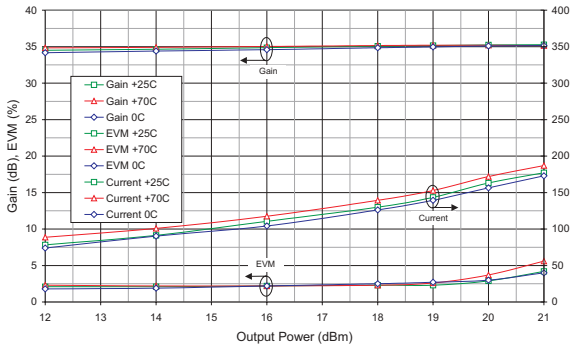


Figure 5: Gain, Current vs. Output Power at 2.437 GHz, 3.3 V (IEEE 802.11b Signal @ 11 Mbps)

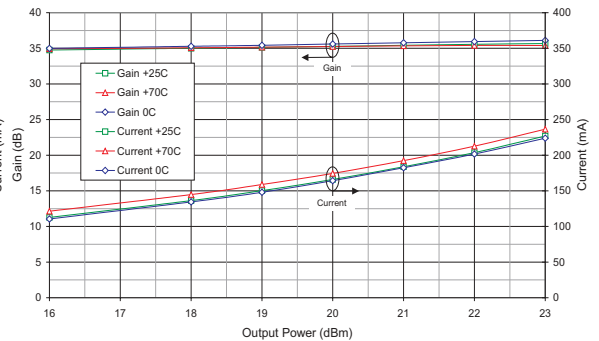


Figure 6: Gain, Current, EVM vs. Output Power at 2.462 GHz, 3.3 V (IEEE 802.11g @ 54 Mbps)

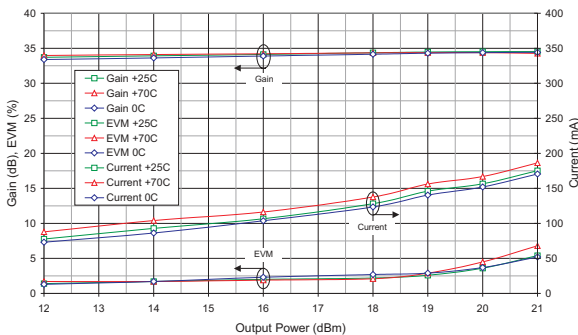


Figure 7: Gain, Current vs. Output Power at 2.462 GHz, 3.3 V (IEEE 802.11b Signal @ 11 Mbps)

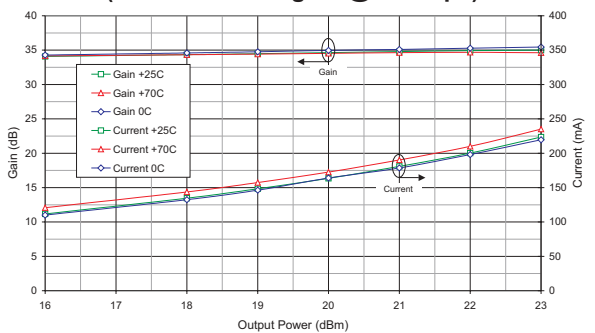


Figure 8: Power Detector Voltage vs. Output Power at 2.412 GHz, 3.3 V (IEEE 802.11g @ 54 Mbps)

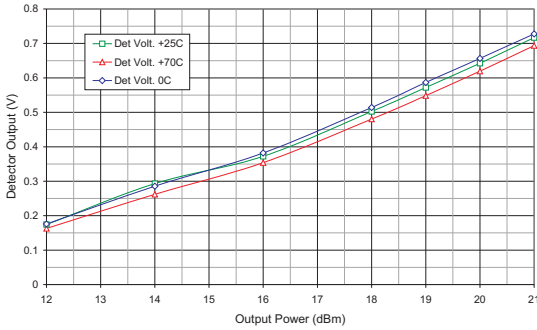


Figure 9: Power Detector Voltage vs. Output Power at 2.412 GHz, 3.3 V (IEEE 802.11b @ 11 Mbps)

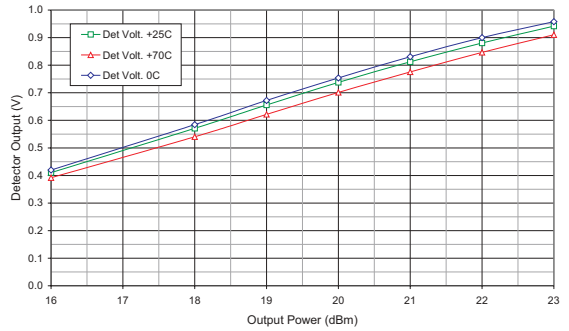


Figure 10: Power Detector Voltage vs. Output Power at 2.437 GHz, 3.3 V (IEEE 802.11g @ 54 Mbps)

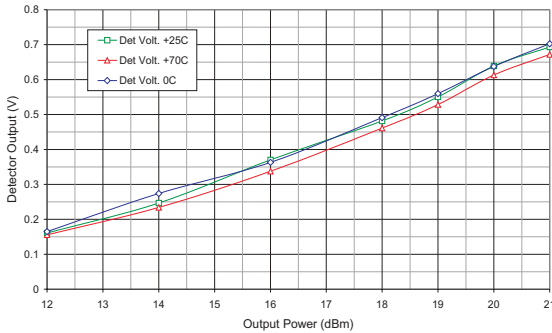


Figure 11: Power Detector Voltage vs. Output Power at 2.437 GHz, 3.3 V (IEEE 802.11b @ 11 Mbps)

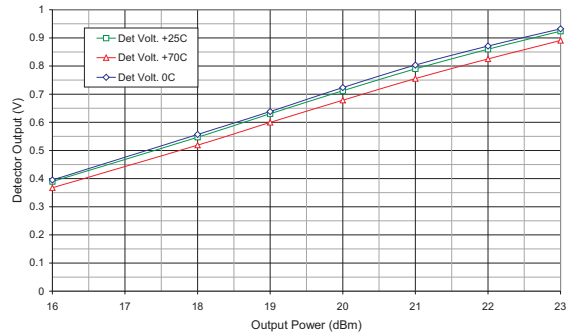


Figure 12: Power Detector Voltage vs. Output Power at 2.462 GHz, 3.3 V (IEEE 802.11g @ 54 Mbps)

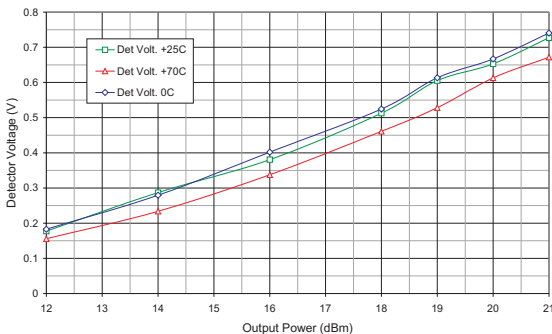


Figure 13: Power Detector Voltage vs. Output Power at 2.462 GHz, 3.3 V (IEEE 802.11b @ 11 Mbps)

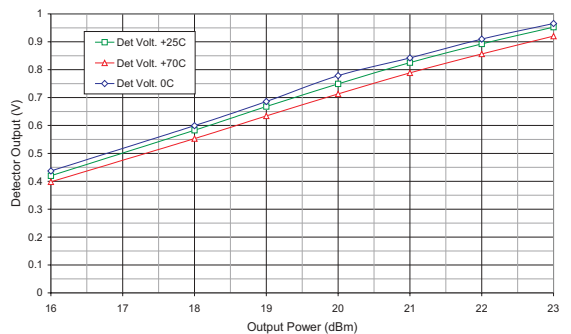


Figure 14: ACPR Sidelobes vs. Output Power at 2.412 GHz, 3.3 V (IEEE 802.11b @ 11 Mbps)

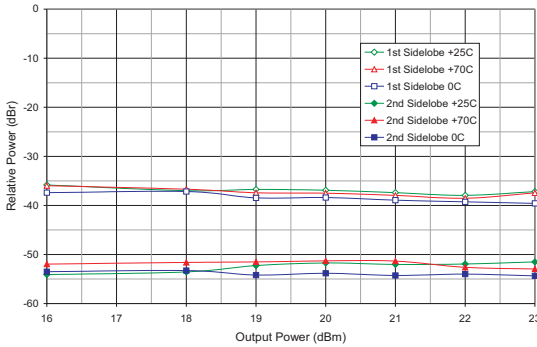


Figure 15: ACPR Sidelobes vs. Output Power at 2.462 GHz, 3.3 V (IEEE 802.11b @ 11 Mbps)

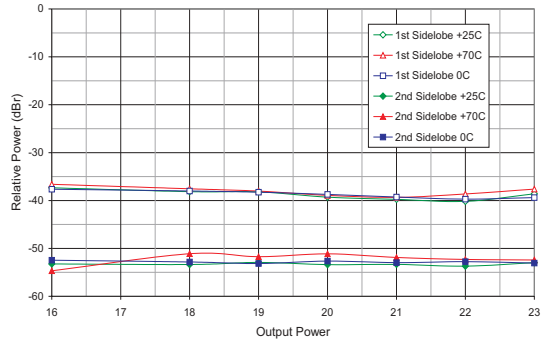


Figure 16: +23 dBm Output Power at 2.412 GHz, 3.3 V (IEEE 802.11b @ 11 Mbps)

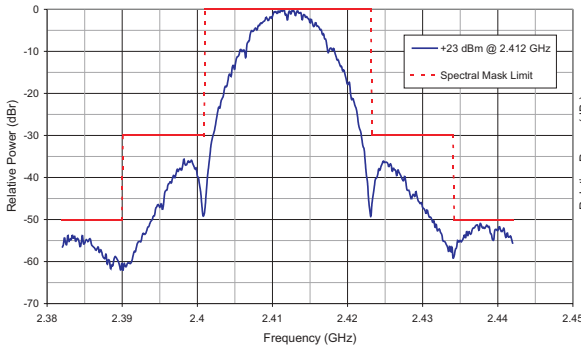


Figure 17: +23 dBm Output Power at 2.462 GHz, 3.3 V (IEEE 802.11b @ 11 Mbps)

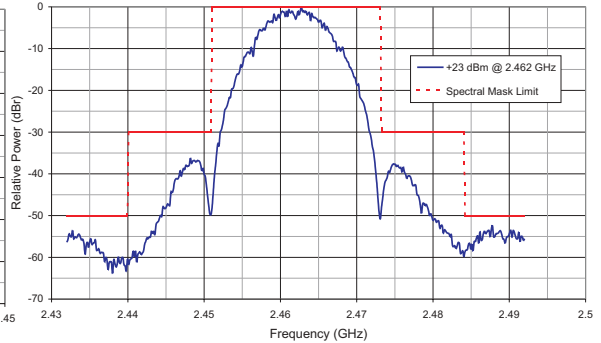
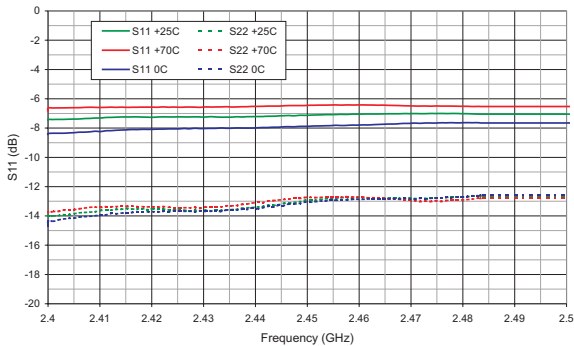


Figure 18: S-Parameter Data S11 and S22, 3.3 V



APPLICATION INFORMATION

****NOTES****

RF traces should be 18 mils wide
with 20 mils of clearance

DC traces should be 8 mils wide with
8 mils of clearance

DNP = Do Not Place

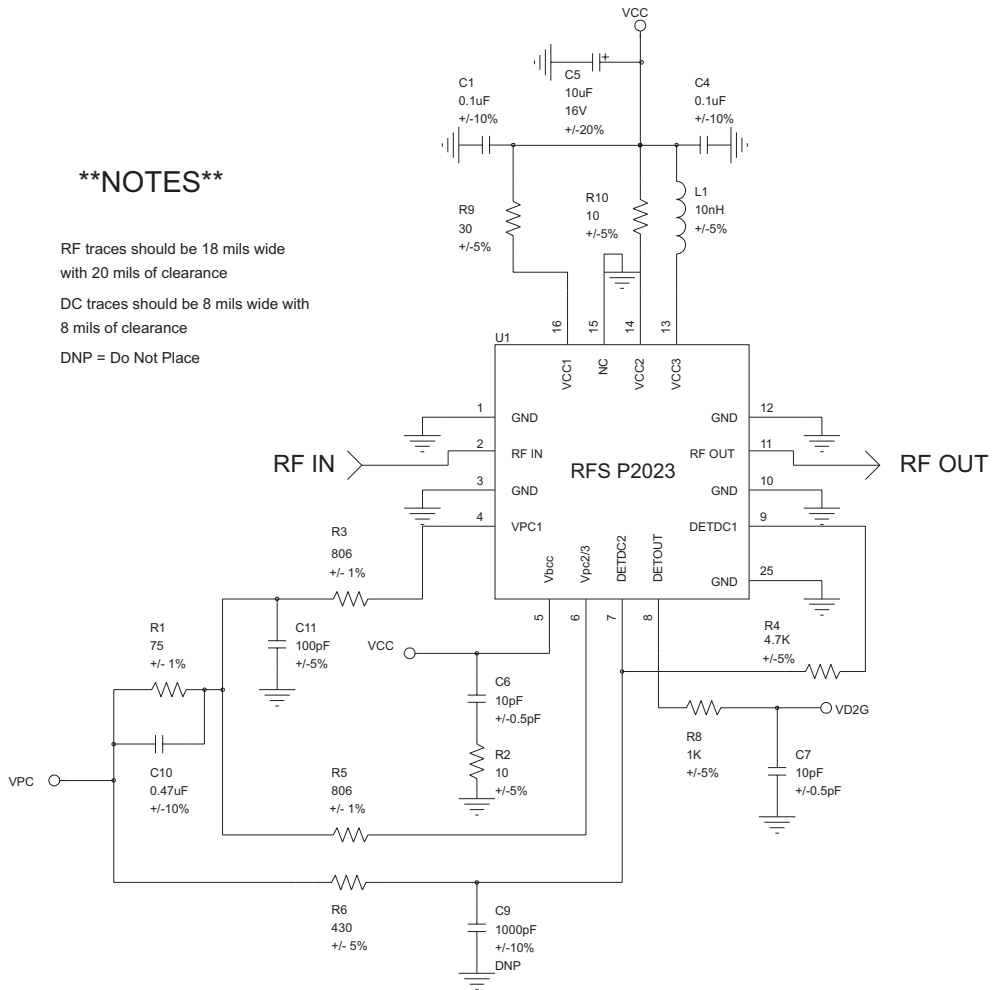
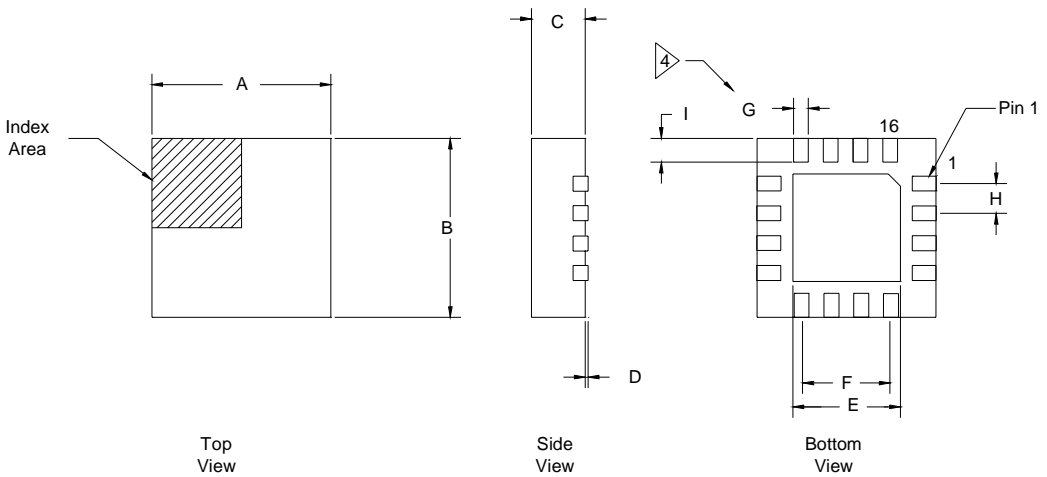


Figure 19: Recommended Application Circuit

PACKAGE OUTLINE



DIMENSION	MILLIMETERS		
	MIN	TYP	MAX
A	2.90	3.00	3.10
B	2.90	3.00	3.10
C	0.80	0.90	1.00
D	0.00	0.02	0.05
E	1.65	1.80	1.95
F	1.50 BSC.		
G	0.225	0.250	0.275
H	0.50 BSC.		
I	0.35	0.40	0.45

1. All dimensions are in millimeters, angles in degrees.
2. The terminal #1 identifier and pad numbering convention shall conform to JESD 95-1 SPP-012
3. Lead coplanarity: 0.05 max.
4. Dimension applies to metalized pad and is measured between 0.25 and 0.30 MM from pad tip.

Figure 20: Package Outline

NOTES

ORDERING INFORMATION

ORDER NUMBER	TEMPERATURE RANGE	PACKAGE DESCRIPTION	COMPONENT PACKAGING
PRFS-P2023-EVL	0 °C to +70 °C	Evaluation Board	1 pc.
PRFS-P2023-005	0 °C to +70 °C	13" Reverse Tape/Reel	2500 pcs.
PRFS-P2023-006	0 °C to +70 °C	13" Forward Tape/Reel	2500 pcs.
PRFS-P2023-007	0 °C to +70 °C	7" Reverse Tape/Reel	1000 pcs.
PRFS-P2023-008	0 °C to +70 °C	7" Forward Tape/Reel	1000 pcs.
PRFS-P2023-009	0 °C to +70 °C	Bulk (Tubes or Tray)	1-999 pcs.

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